## NSN 5961-00-829-1630

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View Online at https://aerobasegroup.com/nsn/5961-00-829-1630 **Inclosure Material:** Metal **Overall Length:** 0.562 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: -100.0 collector to base voltage, dc and -50.0 collector to emitter voltage, dc and -1.5 emitter to base voltage, instantaneous **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 pin and 1 case **Specification Data:** 81349-mil-s-19500/88 government specification Shelf Life: N/a **Unit Of Measure:** 

No

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**Demilitarization:**